

isc N-Channel MOSFET Transistor
2SK3793
FEATURES

- Drain Current : $I_D = 12A @ T_C = 25^\circ C$
- Drain Source Voltage : $V_{DSS} = 100V(\text{Min})$
- Static Drain-Source On-Resistance : $R_{DS(on)} = 125m\Omega (\text{Max}) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

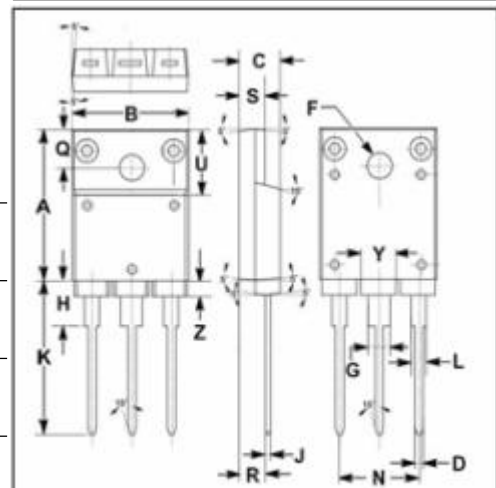
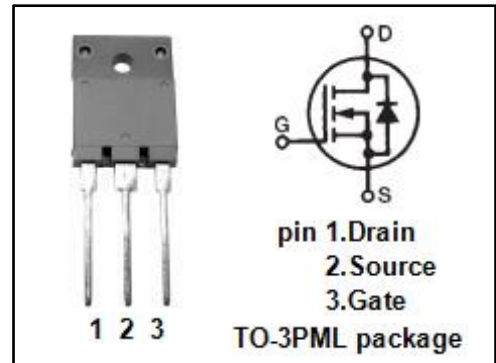
- motor drive, DC-DC converter, power switch and solenoid drive.

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage-Continuous	± 20	V
I_D	Drain Current-Continuous	12	A
I_{DM}	Drain Current-Single Pluse	22	A
P_D	Total Dissipation @ $T_C = 25^\circ C$	20	W
T_J	Max. Operating Junction Temperature	-55~150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	6.25	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	19.90	20.10
B	15.75	16.10
C	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.20
H	5.90	6.10
J	0.595	0.70
K	21.10	22.50
L	1.90	2.25
N	10.80	11.00
O	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Y	4.20	4.90
Z	1.90	2.10

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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1.0mA	100	--	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1.0mA	1.5	2.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 6.0A	--	125	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V; V _{DS} = 0	--	±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 100V; V _{GS} = 0	--	10	uA
V _{SD}	Forward On-Voltage	I _S = 12A; V _{GS} = 0	--	1.5	V

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